



MMBD1501A/1503A/1504A/1505A

High conductance low leakage diode

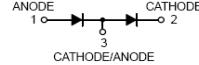


FEATURES

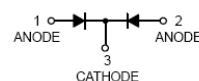
- Two element incorporated into one package.
(Emitter-coupled transistors)
- Reduction of the mounting area and assembly cost by one half.



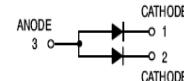
MMBD1501A



MMBD1503A



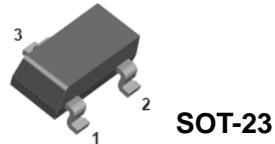
MMBD1504A



MMBD1505A

APPLICATIONS

- For general application.



SOT-23

ORDERING INFORMATION

Type No.	Marking	Package Code
MMBD1501A	A11	SOT-23
MMBD1503A	A13	SOT-23
MMBD1504A	A14	SOT-23
MMBD1505A	A15	SOT-23

MAXIMUM RATING @ Ta=25°C unless otherwise specified

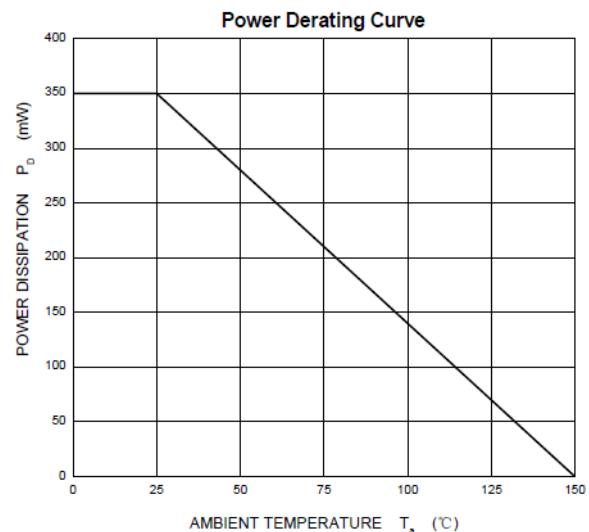
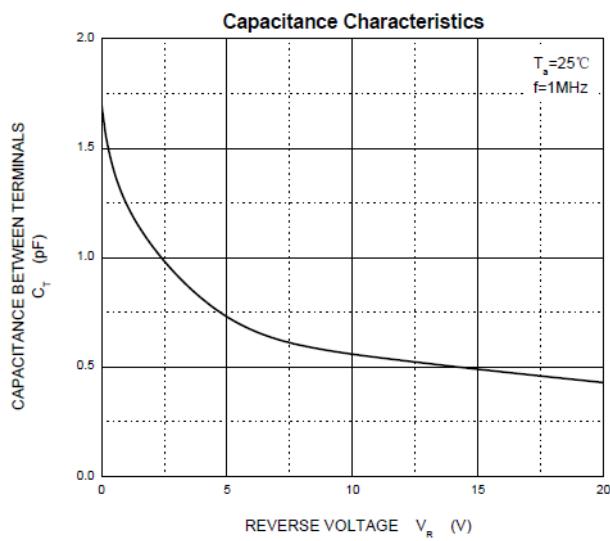
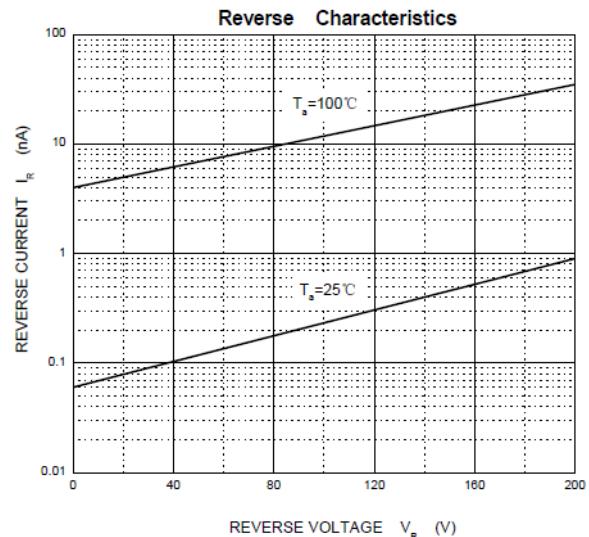
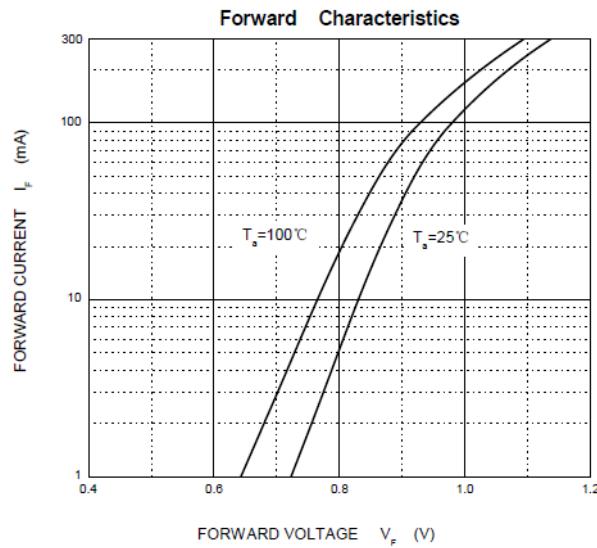
Parameter	Symbol	Limits	Unit
Reverse Voltage	V _R	200	V
Average rectified current	V _{F(AV)}	200	mA
Forward Continuous Current	I _{FM}	200	mA
Recurrent Peak Forward Current	I _{FRM}	700	mA
Peak forward current (1.0s) (1.0m)	I _{FSM}	1.0 2.0	A
Power Dissipation	P _d	350	mW
Thermal resistance,Junction to ambient	R _{θJA}	357	°C/W
Storage temperature	T _{STG}	-55 to +150	°C


ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Reverse Breakdown Voltage	$V_{(BR)R1}$	200			V	$I_R=5\mu A$
Forward voltage	V_F			0.72	V	$I_F=1mA$
				0.83		$I_F=10mA$
				0.95		$I_F=50mA$
				1.1		$I_F=100mA$
				1.3		$I_F=200mA$
				1.5		$I_F=300mA$
Reverse current	I_R			10	nA	$V_R=180V$
Diode Capacitance	C_D			4	pF	$V_R=0V, f=1MHz$



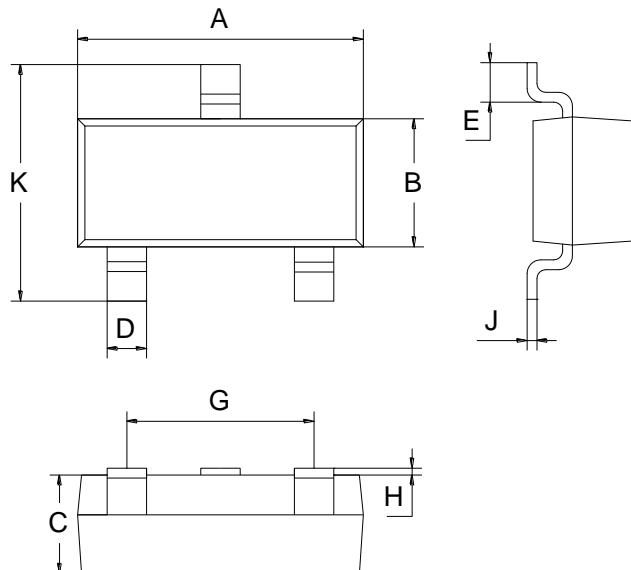
TYPICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified





PACKAGE OUTLINE

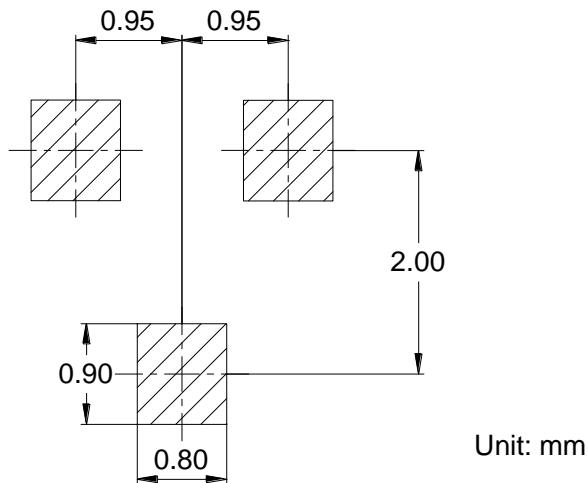
Plastic surface mounted package



SOT-23		
Dim	Min	Max
A	2.70	3.10
B	1.10	1.50
C	0.90	1.10
D	0.30	0.50
E	0.35	0.48
G	1.80	2.00
H	0.02	0.10
J	0.05	0.15
K	2.20	2.60

All Dimensions in mm

SOLDERING FOOTPRINT



PACKAGE INFORMATION

Device	Package	Shipping
MMBD1501A/1503A/1504A/1505A	SOT-23	3000 pcs / Tape & Reel